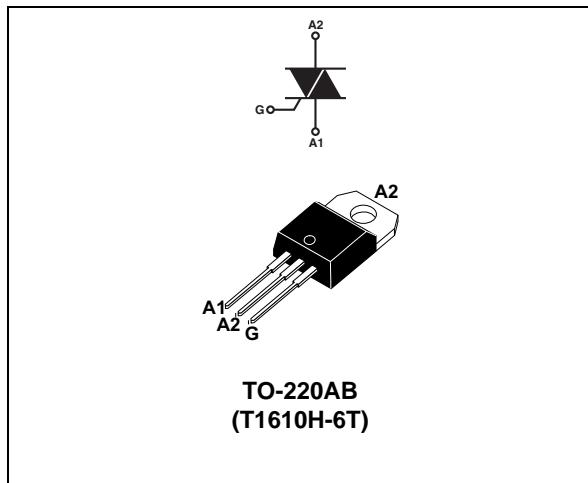


16 A Triac, high temperature and logic level

Datasheet – production data



Features

- Junction temperature up to 150 °C max.
- Logic level gate current: 10 mA
- Repetitive peak off-state voltage: 600 V
- High I_{TSM}
- High thermal cycling performance

Applications

- Electric heater
- Water heater, room heater
- Coffee machine
- Hand dryer
- Thermostat

Description

This clip technology Triac has very high thermal cycling performance, and the design structure presents a higher I_{TSM} . The 150 °C maximum junction temperature of this device offers easier thermal management. Its 10 mA gate current offers direct drive from a microcontroller, mainly for resistive load control.

Table 1. Device summary

Order code	Package	V_{DRM}, V_{RRM}	I_{GT}	$I_{T(RMS)}$
T1610H-6T	TO-220AB	600 V	10 mA	16 A

1 Characteristics

Table 2. Absolute maximum rating ($T_j = 25^\circ\text{C}$, unless otherwise specified)

Symbol	Parameter	Value	Unit	
$I_{T(\text{RMS})}$	On-state rms current (180° conduction angle)	$T_c = 133^\circ\text{C}$	16	A
I_{TSM}	Non repetitive surge peak on-state current, T_j initial = 25°C	$t_p = 16.7 \text{ ms}$	168	A
		$t_p = 20 \text{ ms}$	160	
I^2t	I^2t Value for fusing	$t_p = 10 \text{ ms}$	169	A^2s
dI/dt	Critical rate of rise of on-state current, $I_G = 2 \times I_{GT}$, $t_r \leq 100 \text{ ns}$	$F = 60 \text{ Hz}$	100	$\text{A}/\mu\text{s}$
V_{DRM}, V_{RRM}	Repetitive peak off-state voltage	$T_j = 150^\circ\text{C}$	600	V
V_{DSM}, V_{RSM}	Non repetitive peak off-state voltage	$t_p = 10 \text{ ms}$	700	V
I_{GM}	Peak gate current	$t_p = 20 \mu\text{s}$	4	A
P_{GM}	Peak gate power dissipation	$t_p = 20 \mu\text{s}$	10	W
$P_{G(AV)}$	Average gate power dissipation		1	W
T_{stg}, T_j	Storage junction temperature range Operating junction temperature range		-40 to +150	$^\circ\text{C}$
T_L	Lead temperature for soldering during 10 s		260	$^\circ\text{C}$

Table 3. Electrical characteristics ($T_j = 25^\circ\text{C}$, unless otherwise specified)

Symbol	Test conditions	Quadrant		Value	Unit
I_{GT}	$V_D = 12 \text{ V}$, $R_L = 33 \Omega$	I - II - III	MIN.	0.5	mA
			MAX.	10	mA
V_{GT}	$V_D = 12 \text{ V}$, $R_L = 33 \Omega$	I - II - III	MAX.	1.3	V
V_{GD}	$V_D = V_{DRM}$, $R_L = 3.3 \text{ k}\Omega$, $T_j = 150^\circ\text{C}$	I - II - III	MIN.	0.2	V
I_H	$I_T = 500 \text{ mA}$, gate open	—	MAX.	15	mA
I_L	$I_G = 1.2 I_{GT}$	I - II - III	MAX.	30	mA
dV/dt	$V_D = 67\% \times V_{DRM}$, V_{RRM} , gate open	$T_j = 150^\circ\text{C}$	—	MIN.	$\text{V}/\mu\text{s}$
(dl/dt)c	$(dV/dt)_c = 0.1 \text{ V}/\mu\text{s}$ $(dV/dt)_c = 10 \text{ V}/\mu\text{s}$	$T_j = 150^\circ\text{C}$	—	8.5	A/ms
			—	3	
t_{gt}	$I_{TM} = 13 \text{ A}$, $V_D = 400 \text{ V}$, $I_G = 100 \text{ mA}$, $dI_G/dt = 100 \text{ mA}/\mu\text{s}$, $R_L = 30 \Omega$	—	TYP.	2	μs

Table 4. Static characteristics

Symbol	Test conditions		Value	Unit
V_{TM}	$I_{TM} = 22.5 \text{ A}$, $t_p = 380 \mu\text{s}$	$T_j = 25^\circ\text{C}$	1.55	V
V_{to}	Threshold voltage	$T_j = 150^\circ\text{C}$		V
R_d	Dynamic resistance	$T_j = 150^\circ\text{C}$		$\text{m}\Omega$
I_{DRM} , I_{RRM}	$V_D = V_{DRM}$, $V_R = V_{RRM}$	$T_j = 25^\circ\text{C}$		μA
		$T_j = 150^\circ\text{C}$		mA

Table 5. Thermal resistance

Symbol	Parameter	Value	Unit
$R_{th(j-c)}$	Junction to case (AC)	1.0	$^\circ\text{C/W}$
$R_{th(j-a)}$	Junction to ambient (AC)	60	$^\circ\text{C/W}$

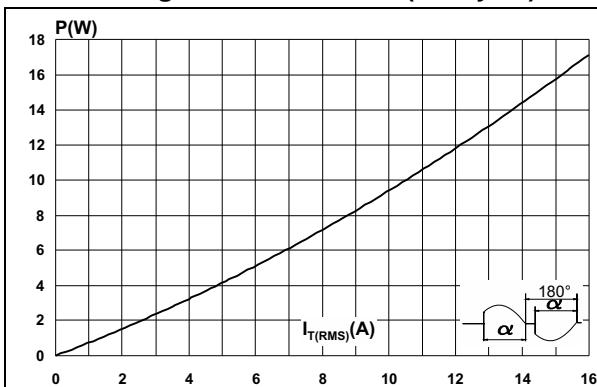
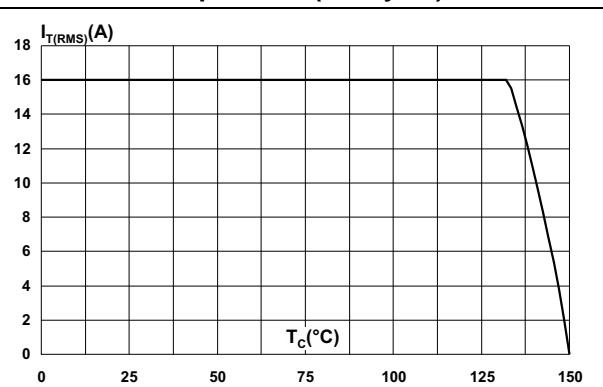
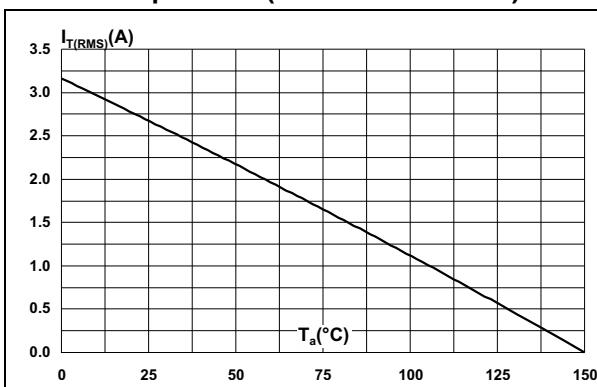
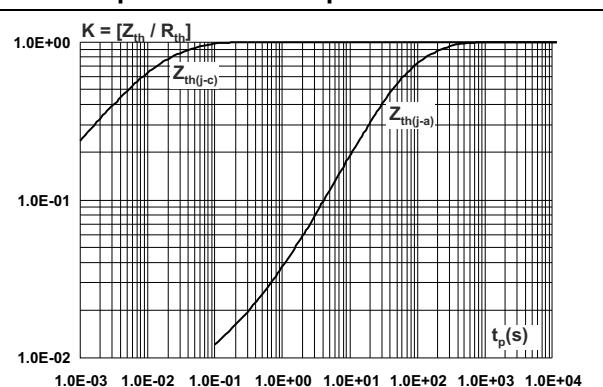
Figure 1. Maximum power dissipation versus average on-state current (full cycle)**Figure 2. On-state rms current versus case temperature (full cycle)****Figure 3. On-state rms current versus ambient temperature (free air convection)****Figure 4. Relative variation of thermal impedance versus pulse duration**

Figure 5. Relative variation of gate trigger current and voltage versus junction temperature (typical values)

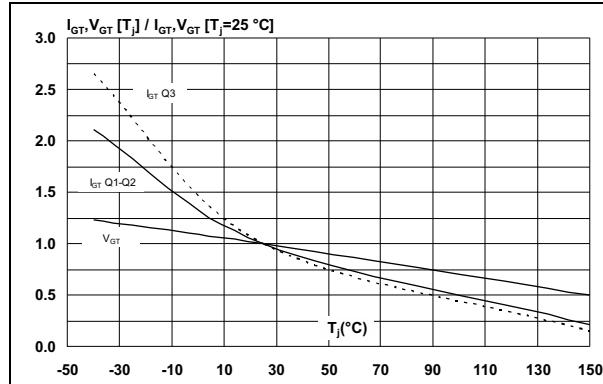


Figure 7. Relative variation of dV/dt immunity versus junction temperature (typical values)

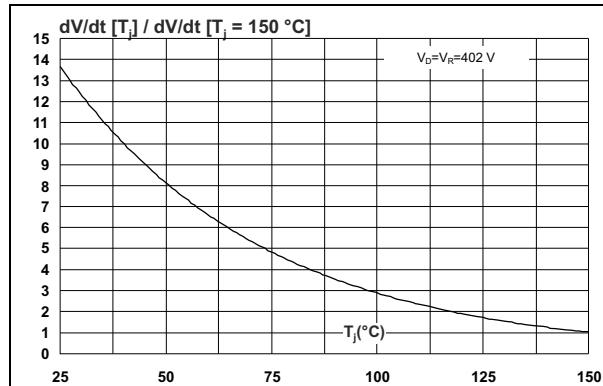


Figure 9. Relative variation of critical rate of decrease of main current (di/dt)c versus reapplyed (dV/dt)c

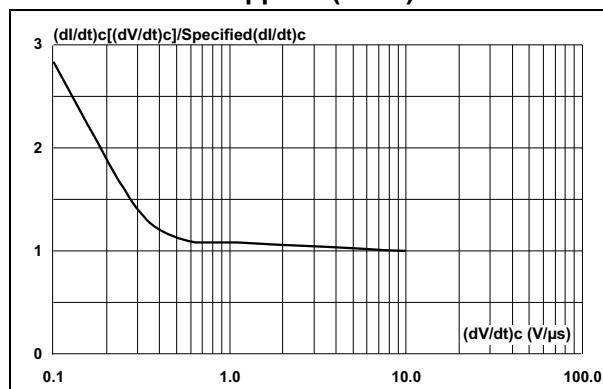


Figure 6. Relative variation of holding and latching current versus junction temperature (typical values)

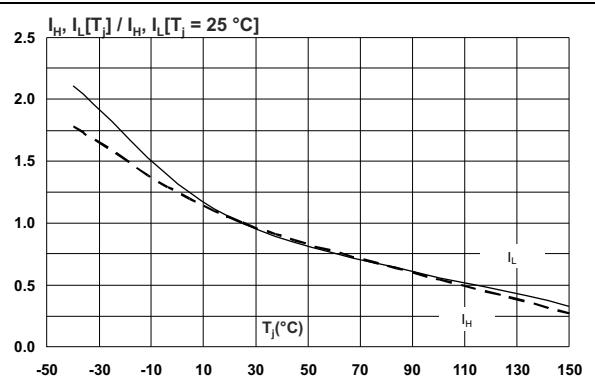


Figure 8. Relative variation of critical rate of decrease of main current (di/dt)c versus junction temperature (typical values)

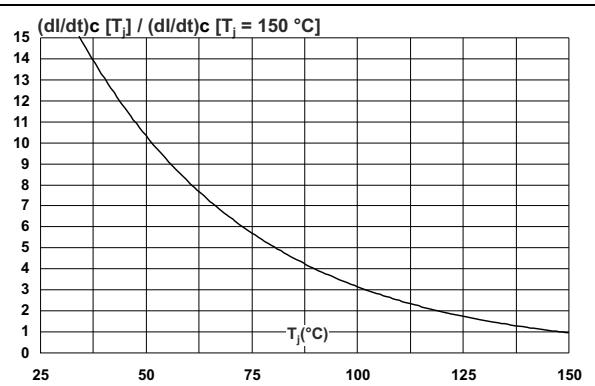


Figure 10. Surge peak on-state current versus number of cycles

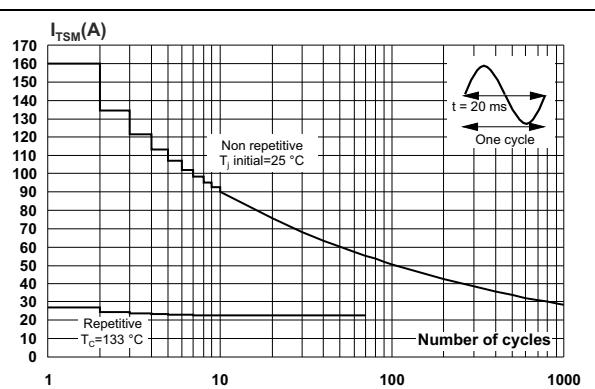


Figure 11. Non repetitive surge peak on-state current for a sinusoidal pulse with width $t_p < 10$ ms, and corresponding value of I^2t

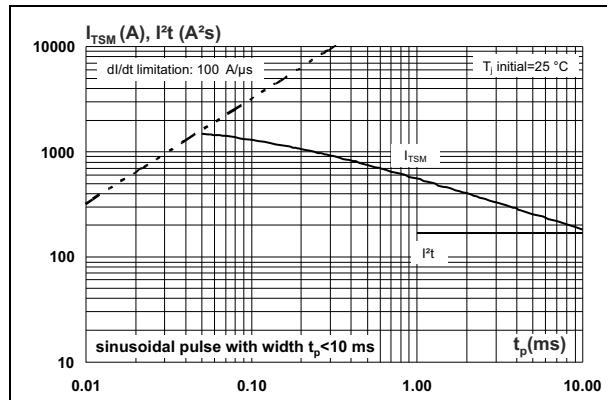


Figure 12. On-state characteristics (maximum values)

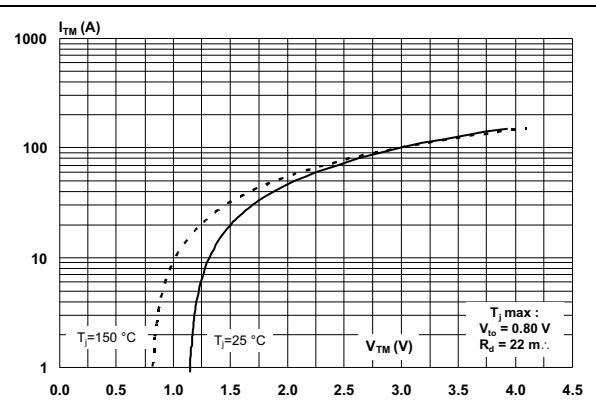
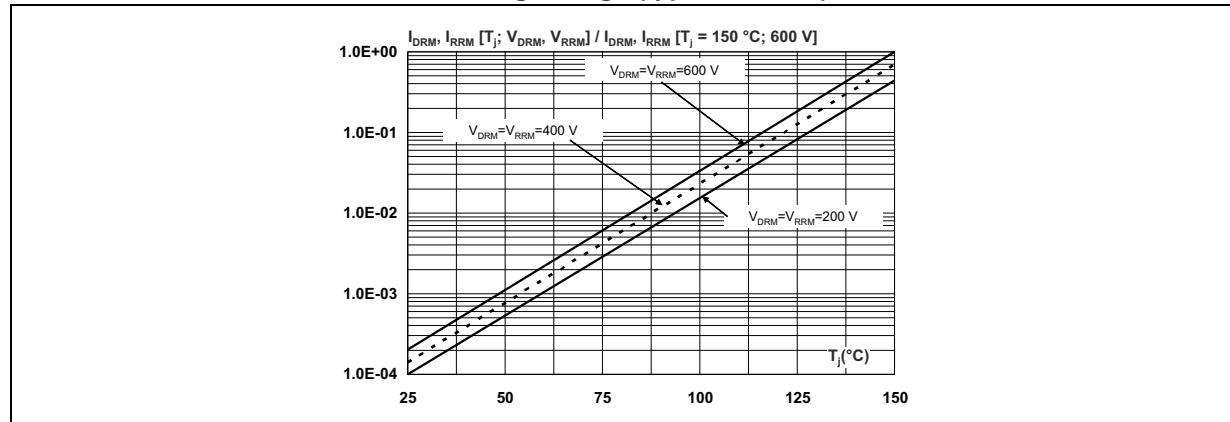


Figure 13. Relative variation of leakage current versus junction temperature for different values of blocking voltage (typical values)



2 Package information

- Epoxy meets UL94, V0
- Recommended torque value: 0.4 to 0.6 N·m

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com.
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Figure 14. TO-220AB dimension definitions

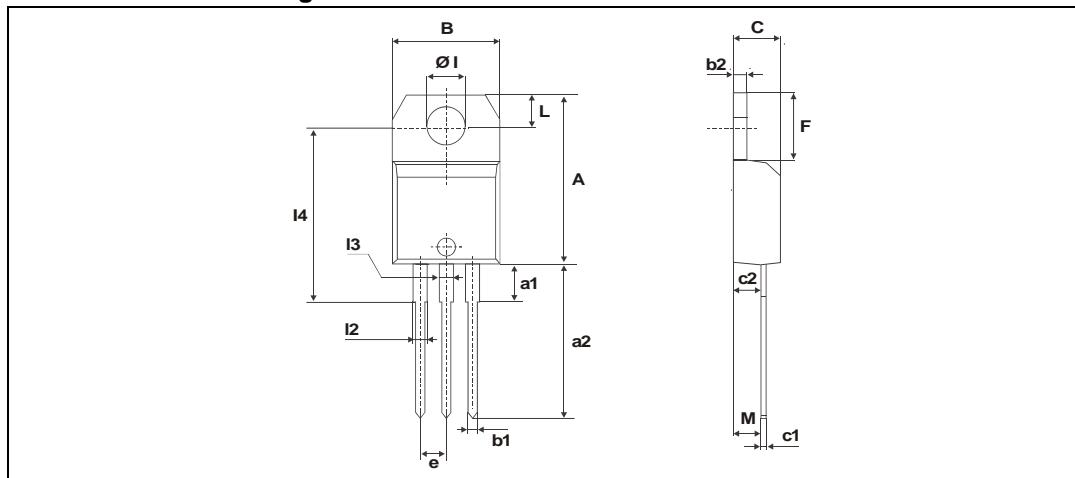


Table 6. TO-220AB dimension values

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	15.20		15.90	0.598		0.625
a1		3.75			0.147	
a2	13.00		14.00	0.511		0.551
B	10.00		10.40	0.393		0.409
b1	0.61		0.88	0.024		0.034
b2	1.23		1.32	0.048		0.051
C	4.40		4.60	0.173		0.181
c1	0.49		0.70	0.019		0.027
c2	2.40		2.72	0.094		0.107
e	2.40		2.70	0.094		0.106
F	6.20		6.60	0.244		0.259
ØI	3.75		3.85	0.147		0.151
I4	15.80	16.40	16.80	0.622	0.646	0.661
L	2.65		2.95	0.104		0.116
I2	1.14		1.70	0.044		0.066
I3	1.14		1.70	0.044		0.066
M		2.60			0.102	

3 Ordering information

Figure 15. Ordering information scheme

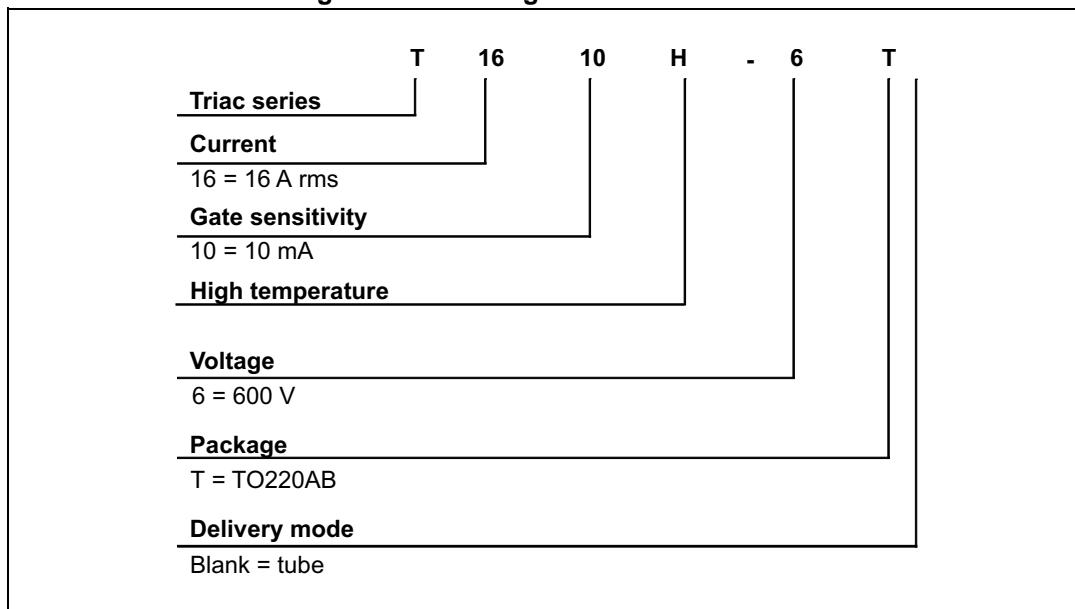


Table 7. Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
T1610H-6T	T1610H-6T	TO-220AB	2.3	50	Tube

4 Revision history

Table 8. Document revision history

Date	Revision	Changes
31-May-2013	1	First issue.